

At page 10, line 24, please replace "masking" with --mask--.

At page 11, line 6, please replace "hard mask 135" with
--mask layer 135--.

At page 11, line 9, please replace "masking" with --mask--.

At page 11, line 17, please delete "region".

At page 11, lines 2 and 21, please replace "masking" with
--mask--.

At page 12, line 8, please replace "masking" with --mask--.

At page 13, line 26, please replace "P-well" with --P-type
well--.

At page 14, line 1, please replace "P-well" with --P-type
well--.

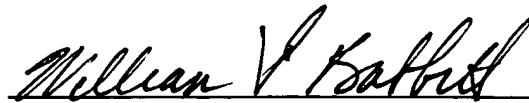
At page 17, line 8, please replace "of a CMOS circuit to
optimum" with --to improve NMOS and PMOS--.

At page 17, line 13, please delete "layer".

Respectfully submitted,

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